

To our customers,

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## Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

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# HAF1002(L), HAF1002(S)

Silicon P Channel MOS FET Series  
Power Switching

REJ03G1133-0200  
(Previous: ADE-208-586)  
Rev.2.00  
Sep 07, 2005

## Description

This FET has the over temperature shut-down capability sensing to the junction temperature.

This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc.

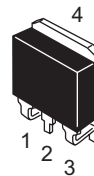
## Features

- Logic level operation ( $-4$  to  $-6$  V Gate drive)
- High endurance capability against to the short circuit
- Built-in the over temperature shut-down circuit
- Latch type shut-down operation (Need 0 voltage recovery)

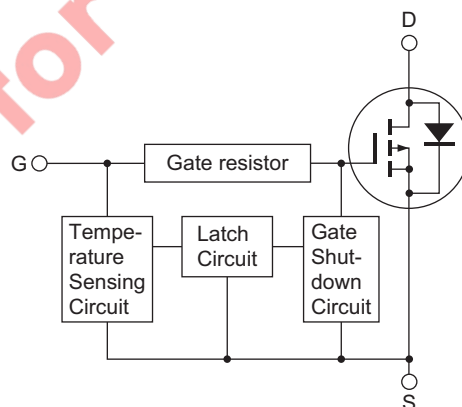
## Outline

RENESAS Package code: PRSS0004AE-A  
(Package name: LDKPAK (L) )

RENESAS Package code: PRSS0004AE-B  
(Package name: LDKPAK (S)-(1) )



1. Gate
2. Drain
3. Source
4. Drain



## Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Drain to source voltage	V <sub>DSS</sub>	-60	V
Gate to source voltage	V <sub>GSS</sub>	-16	V
	V <sub>GSS</sub>	3	V
Drain current	I <sub>D</sub>	-15	A
Drain peak current	I <sub>D (pulse)</sub> <sup>Note 1</sup>	-30	A
Body-drain diode reverse drain current	I <sub>DR</sub>	-15	A
Channel dissipation	P <sub>ch</sub> <sup>Note 2</sup>	50	W
Channel temperature	T <sub>ch</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

Notes: 1. PW ≤ 10 μs, duty cycle ≤ 1%

2. Value at Tc = 25°C

## Typical Operation Characteristics

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	-3.5	—	—	V	
	V <sub>IL</sub>	—	—	-1.2	V	
Input current (Gate non shut down)	I <sub>IH1</sub>	—	—	-100	μA	V <sub>i</sub> = -8 V, V <sub>DS</sub> = 0
	I <sub>IH2</sub>	—	—	-50	μA	V <sub>i</sub> = -3.5 V, V <sub>DS</sub> = 0
	I <sub>IL</sub>	—	—	-1	μA	V <sub>i</sub> = -1.2 V, V <sub>DS</sub> = 0
Input current (Gate shut down)	I <sub>IH (sd) 1</sub>	—	-0.8	—	mA	V <sub>i</sub> = -8 V, V <sub>DS</sub> = 0
	I <sub>IH (sd) 2</sub>	—	-0.35	—	mA	V <sub>i</sub> = -3.5 V, V <sub>DS</sub> = 0
Shut down temperature	T <sub>sd</sub>	—	175	—	°C	Channel temperature
Gate operation voltage	V <sub>OP</sub>	-3.5	—	-13	V	

## Electrical Characteristics

(Ta = 25°C)

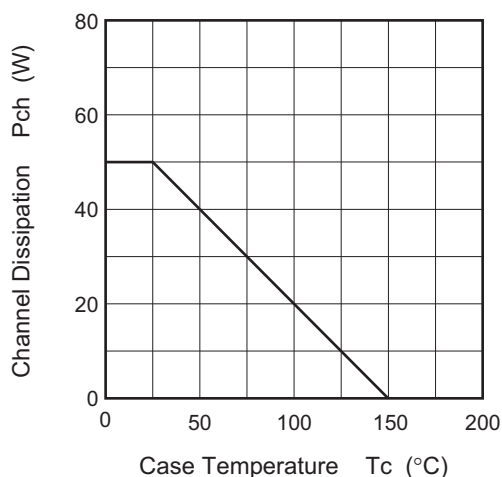
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain current	$I_{D1}$	-7	—	—	A	$V_{GS} = -3.5 \text{ V}$ , $V_{DS} = -2 \text{ V}$
	$I_{D2}$	—	—	-10	mA	$V_{GS} = -1.2 \text{ V}$ , $V_{DS} = -2 \text{ V}$
Drain to source breakdown voltage	$V_{(BR) DSS}$	-60	—	—	V	$I_D = -10 \text{ mA}$ , $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR) GSS}$	-16	—	—	V	$I_G = -100 \mu\text{A}$ , $V_{DS} = 0$
	$V_{(BR) GSS}$	3	—	—	V	$I_G = 100 \mu\text{A}$ , $V_{DS} = 0$
Gate to source leak current	$I_{GSS1}$	—	—	-100	$\mu\text{A}$	$V_{GS} = -8 \text{ V}$ , $V_{DS} = 0$
	$I_{GSS2}$	—	—	-50	$\mu\text{A}$	$V_{GS} = -3.5 \text{ V}$ , $V_{DS} = 0$
	$I_{GSS3}$	—	—	-1	$\mu\text{A}$	$V_{GS} = -1.2 \text{ V}$ , $V_{DS} = 0$
	$I_{GSS4}$	—	—	100	$\mu\text{A}$	$V_{GS} = 2.4 \text{ V}$ , $V_{DS} = 0$
Input current (shut down)	$I_{GS (op) 1}$	—	-0.8	—	mA	$V_{GS} = -8 \text{ V}$ , $V_{DS} = 0$
	$I_{GS (op) 2}$	—	-0.35	—	mA	$V_{GS} = -3.5 \text{ V}$ , $V_{DS} = 0$
Zero gate voltage drain current	$I_{DSS}$	—	—	-250	$\mu\text{A}$	$V_{DS} = -50 \text{ V}$ , $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS (off)}$	-1.1	—	-2.25	V	$I_D = -1 \text{ mA}$ , $V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	$R_{DS (on)}$	—	100	130	$\text{m}\Omega$	$I_D = -7.5 \text{ A}$ , $V_{GS} = -4 \text{ V}$ <sup>Note 3</sup>
	$R_{DS (on)}$	—	70	90	$\text{m}\Omega$	$I_D = -7.5 \text{ A}$ , $V_{GS} = -10 \text{ V}$ <sup>Note 3</sup>
Forward transfer admittance	$ y_{fs} $	5	10	—	S	$I_D = -7.5 \text{ A}$ , $V_{DS} = -10 \text{ V}$ <sup>Note 3</sup>
Output capacitance	$C_{oss}$	—	610	—	pF	$V_{DS} = -10 \text{ V}$ , $V_{GS} = 0$ $f = 1 \text{ MHz}$
Turn-on delay time	$t_{d (on)}$	—	7.5	—	$\mu\text{s}$	$I_D = -7.5 \text{ A}$ $V_{GS} = -5 \text{ V}$ $R_L = 4 \Omega$
Rise time	$t_r$	—	36	—	$\mu\text{s}$	
Turn-off delay time	$t_{d (off)}$	—	32	—	$\mu\text{s}$	
Fall time	$t_f$	—	29	—	$\mu\text{s}$	
Body-drain diode forward voltage	$V_{DF}$	—	-1.0	—	V	$I_F = -15 \text{ A}$ , $V_{GS} = 0$
Body-drain diode reverse recovery time	$t_{rr}$	—	200	—	ns	$I_F = -15 \text{ A}$ , $V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time <sup>Note4</sup>	$t_{os1}$	—	3.7	—	ms	$V_{GS} = -5 \text{ V}$ , $V_{DD} = -12 \text{ V}$
	$t_{os2}$	—	1	—	ms	$V_{GS} = -5 \text{ V}$ , $V_{DD} = -24 \text{ V}$

Notes: 3. Pulse test

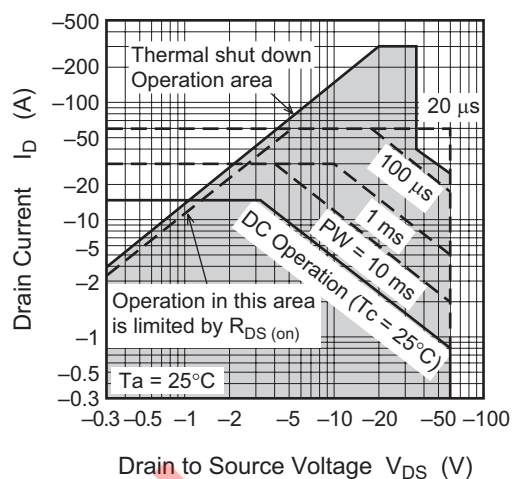
4. Include the time shift based on increasing of channel temperature when operate under over load condition.

## Main Characteristics

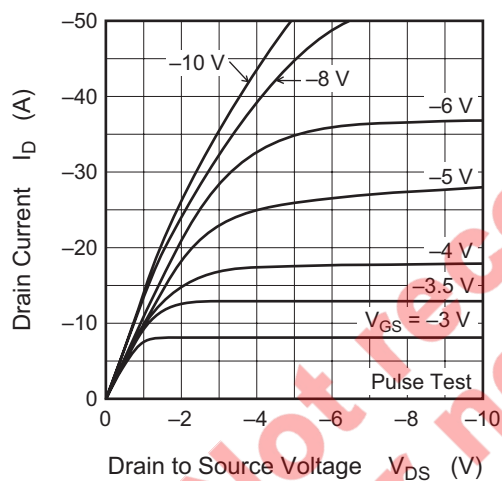
Power vs. Temperature Derating



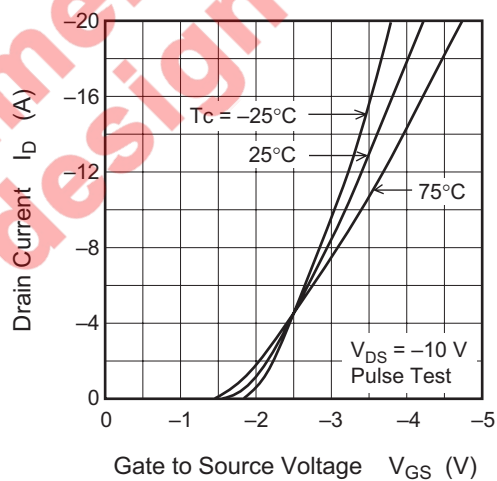
Maximum Safe Operation Area



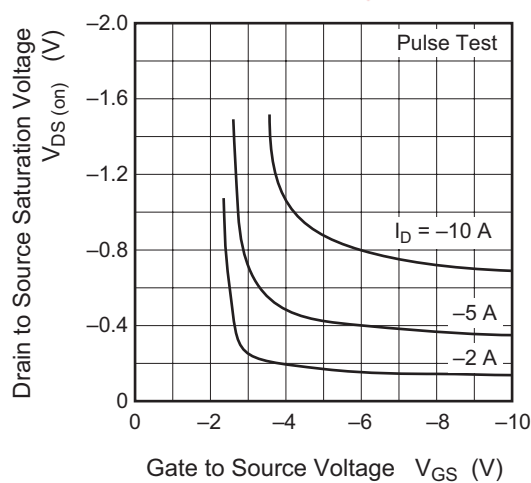
Typical Output Characteristics



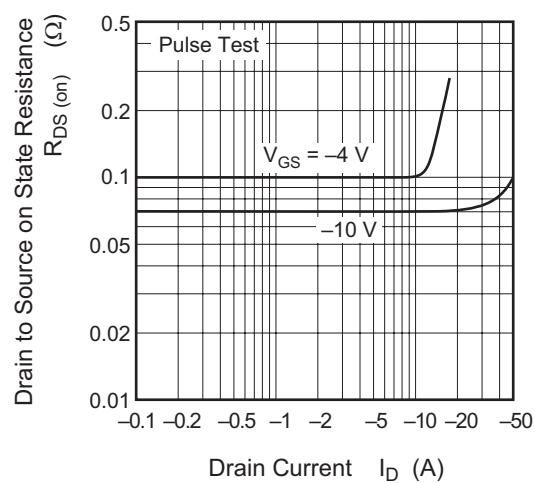
Typical Transfer Characteristics

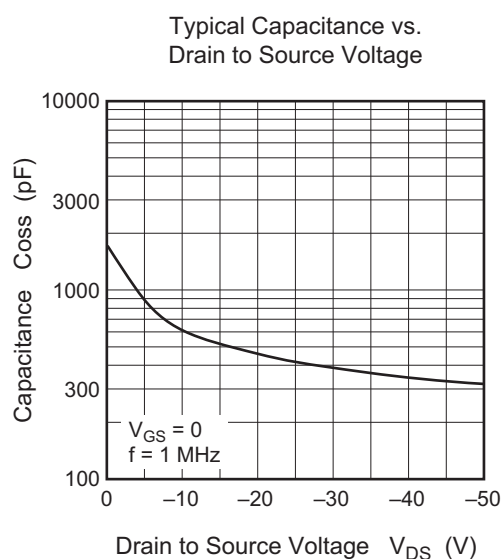
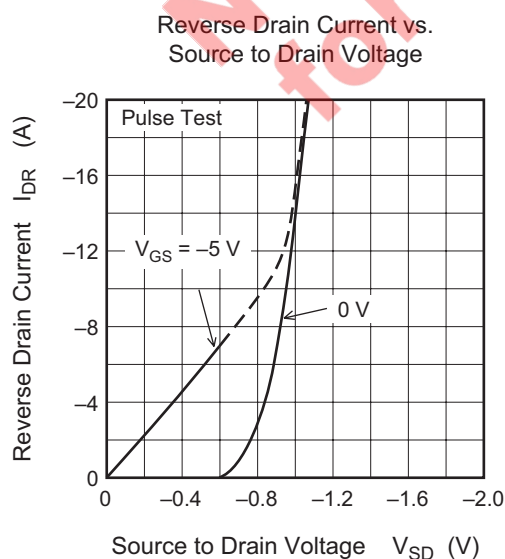
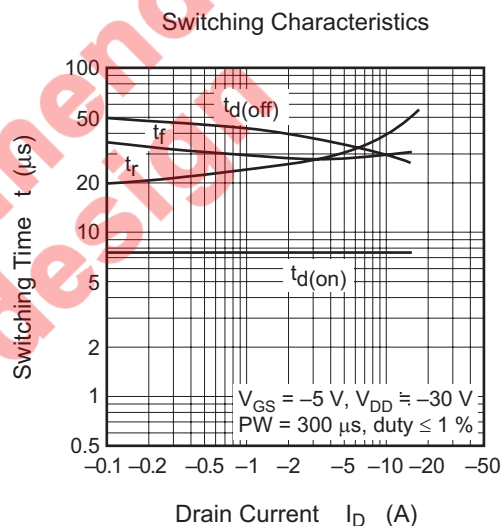
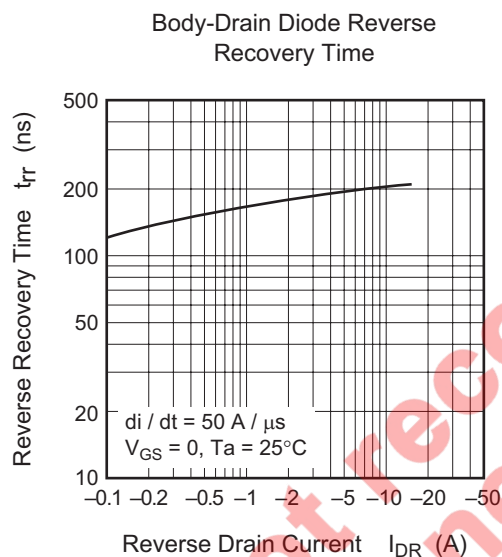
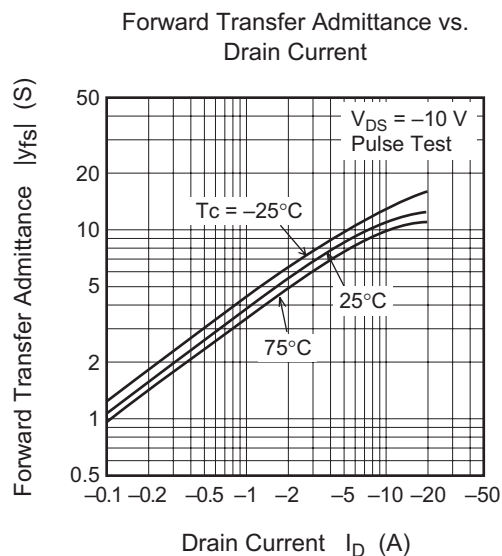
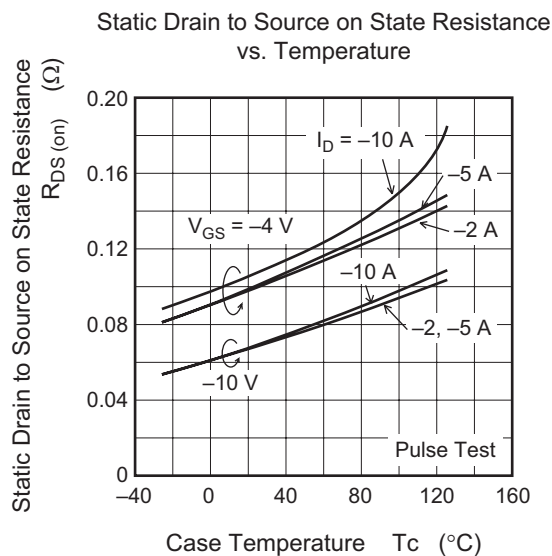


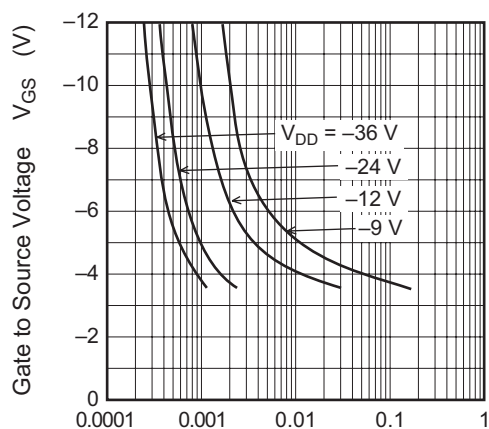
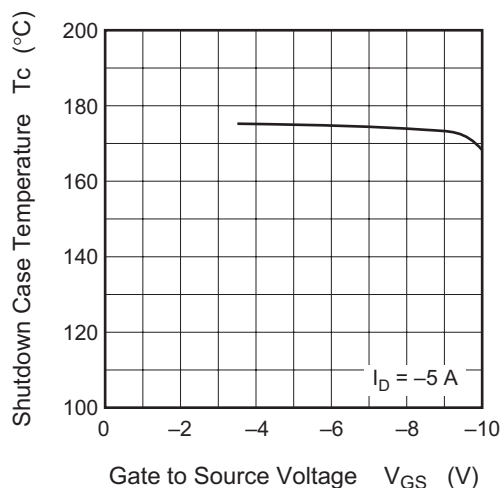
Drain to Source Saturation Voltage vs. Gate to Source Voltage



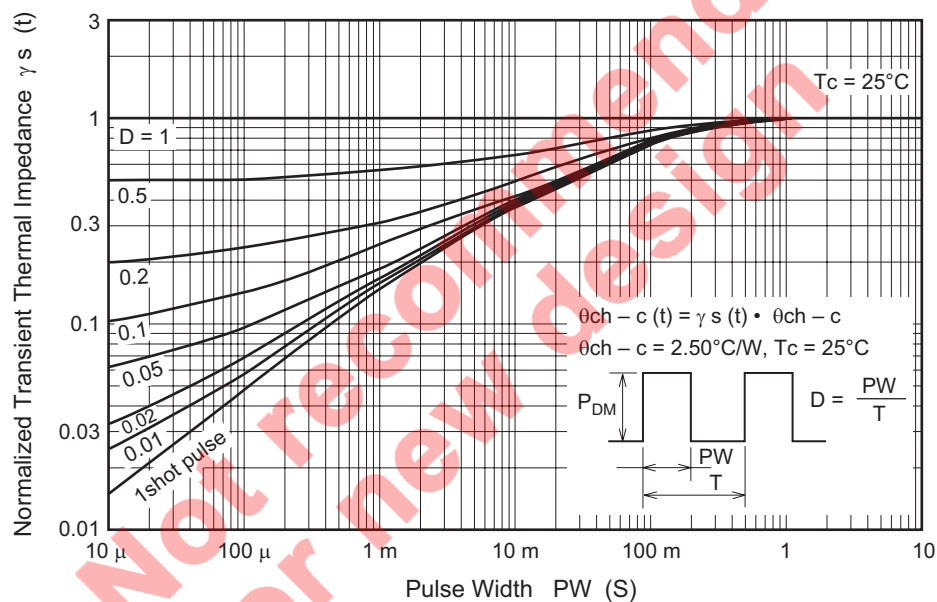
Static Drain to Source on State Resistance vs. Drain Current



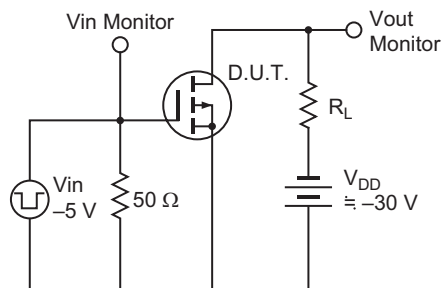


Gate to Source Voltage vs.  
Shutdown Time of Load-Short TestShutdown Time of Load-Short Test  $PW$  (S)Shutdown Case Temperature vs.  
Gate to Source Voltage

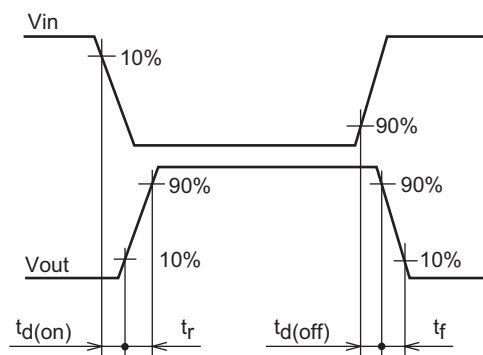
Normalized Transient Thermal Impedance vs. Pulse Width



Switching Time Test Circuit

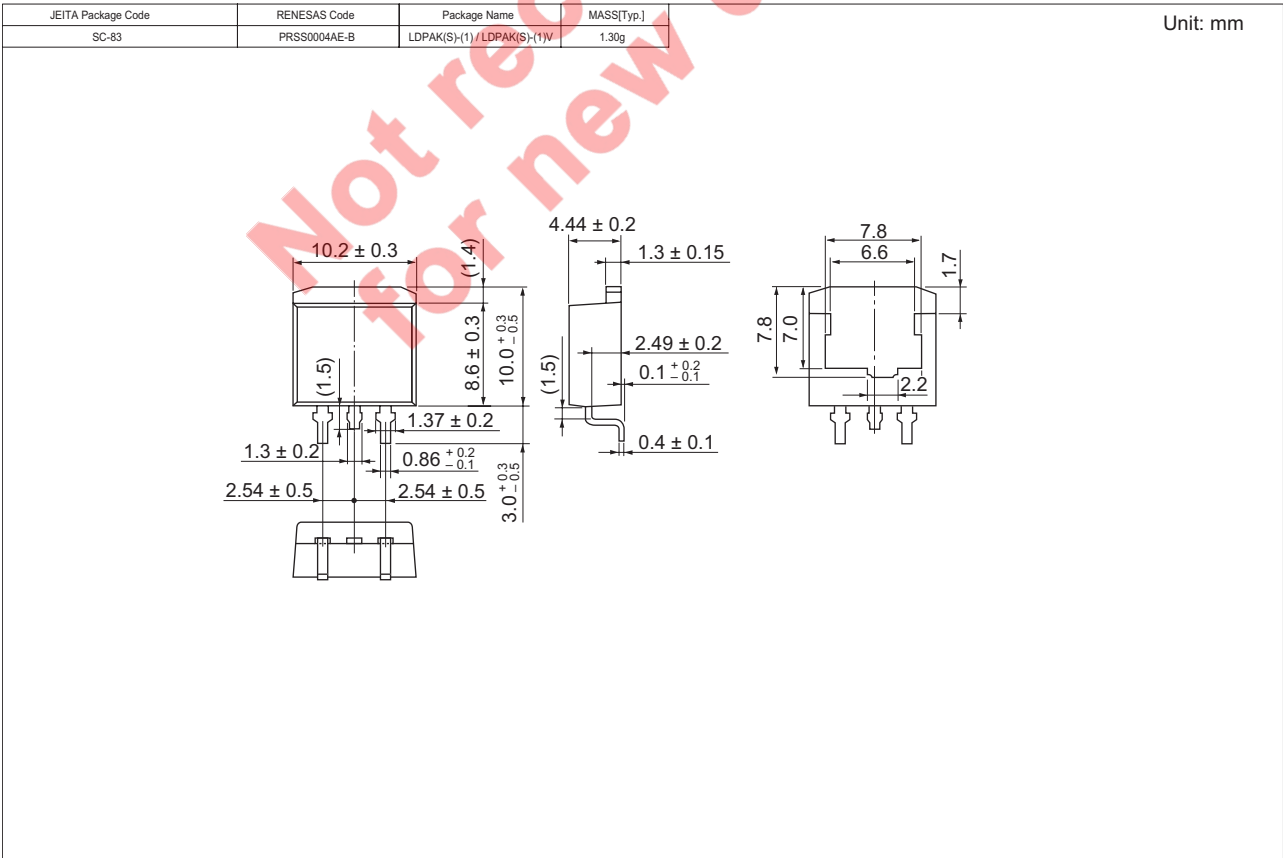
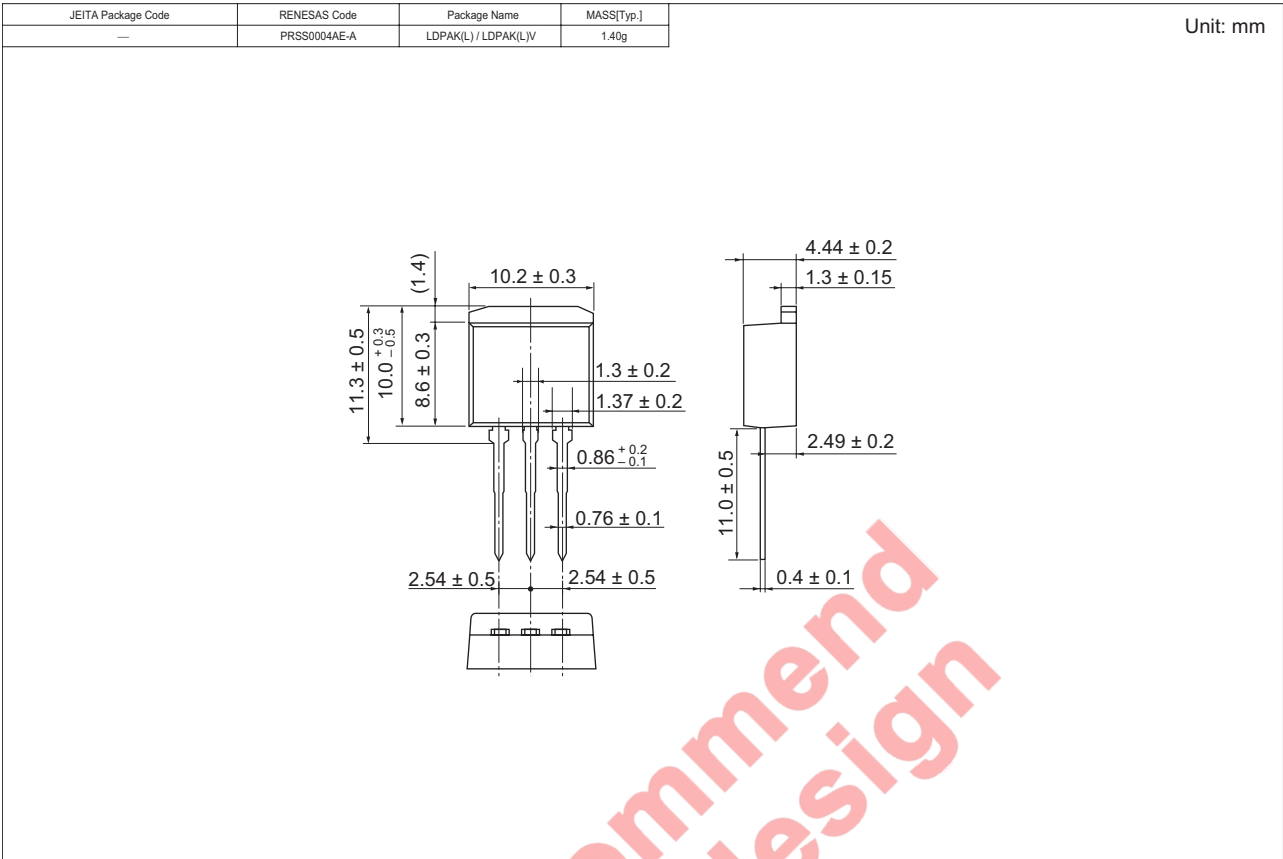


Waveform





Package Dimensions



### Ordering Information

Part Name	Quantity	Shipping Container
HAF1002-90L	Max: 50 pcs/sack	Sack
HAF1002-90S	Max: 50 pcs/sack	Sack
HAF1002-90STL	1000 pcs/Reel	Embossed tape
HAF1002-90STR	1000 pcs/Reel	Embossed tape

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for new design

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